

• Product Summary

Part #	V _{DS}	R _{DS(on).typ} (@V _{GS} =4.5V)	R _{DS(on).typ} (@V _{GS} =2.5V)	I _D
EFM2301S	-20V	105mΩ	135mΩ	-2.5A

• Features

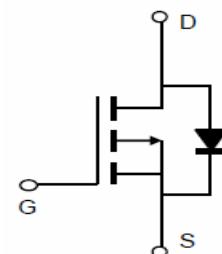
- Low R_{DS(on)} @ V_{GS}=-4.5V
- -2.5V Logic Level Control
- P Channel SOT23 Package
- Pb-Free, RoHS Compliant

• Application

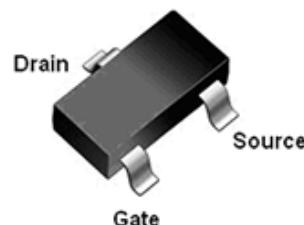
- High-side Load Switch
- Switching Circuits
- High Speed line Driver

• Ordering Information:

Part NO.	EFM2301S
Marking	A1SHB
Packing Information	REEL TAPE
Basic ordering unit (pcs)	3000



P-Channel MOSFET



SOT- 23

HF

• Absolute Maximum Ratings (T_C=25°C)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-20	V
Gate-Source Voltage	V _{GS}	±12	V
Drain Current-Continuous	I _D	-2.5	A
Drain Current-Pulsed (Note 1)	I _{DM}	-9	A
Maximum Power Dissipation	P _D	1	W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 To 150	°C

• Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	125	°C/W
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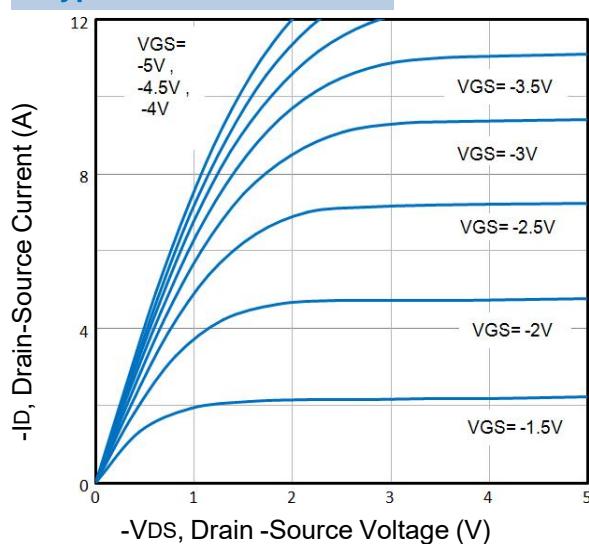
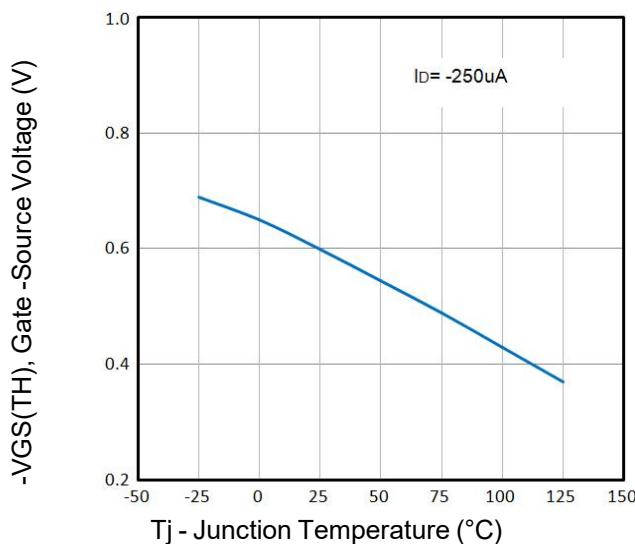
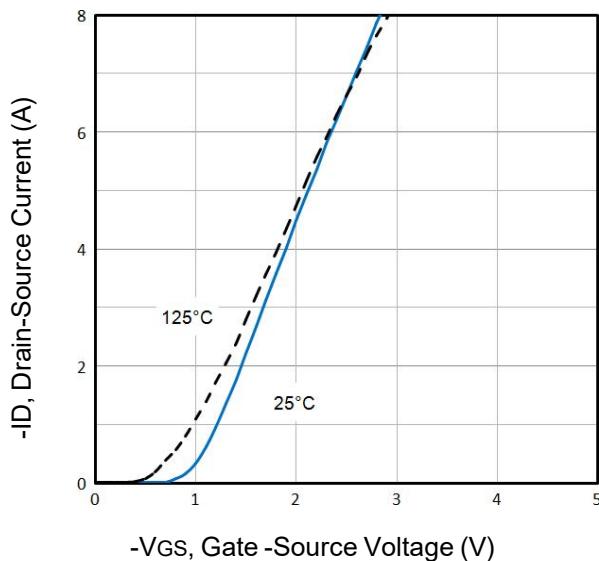
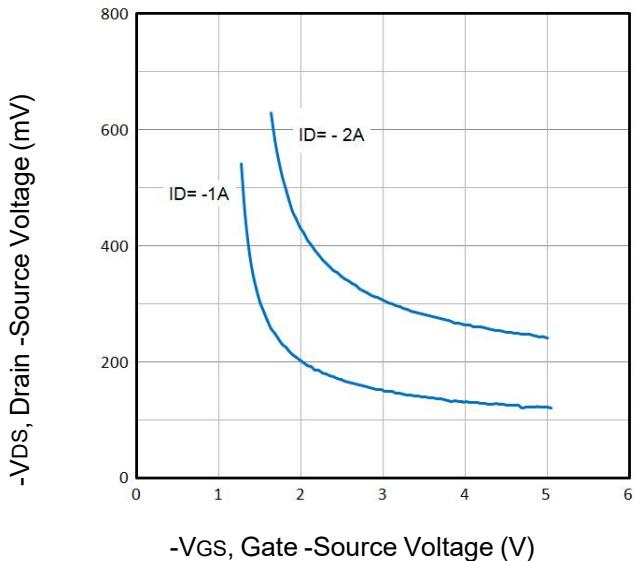
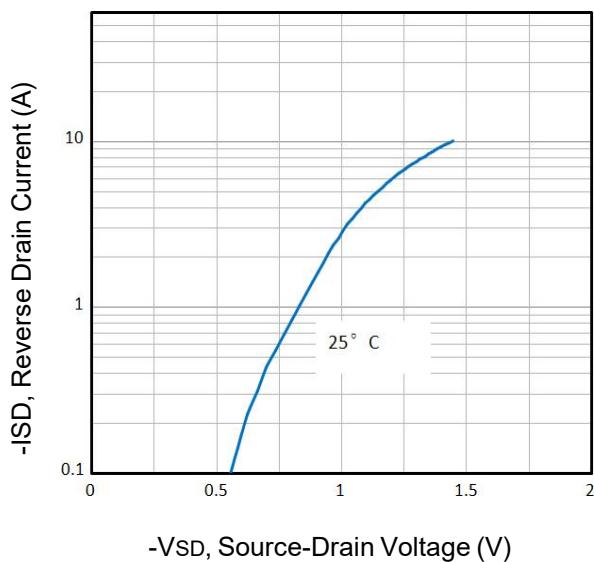
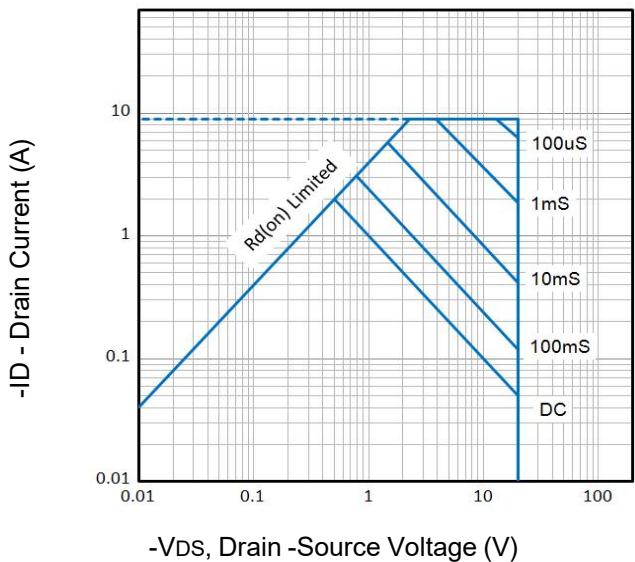
• Static Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise stated)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V} I_{\text{D}}=-250\mu\text{A}$	-20	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=-20\text{V} V_{\text{GS}}=0\text{V}$	--	--	-1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 12\text{V} V_{\text{DS}}=0\text{V}$	--	--	± 100	nA
On Characteristics <small>(Note 3)</small>						
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}} I_{\text{D}}=-250\mu\text{A}$	-0.4	-0.6	-1.0	V
Drain-Source On-State Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}}=-4.5\text{V} I_{\text{D}}=-2.5\text{A}$	--	105	115	$\text{m}\Omega$
		$V_{\text{GS}}=-2.5\text{V} I_{\text{D}}=-1\text{A}$	--	135	145	$\text{m}\Omega$
Dynamic Characteristics <small>(Note 4)</small>						
Input Capacitance	C_{iss}	$V_{\text{DS}}=-10\text{V} V_{\text{GS}}=0\text{V}$ $F=1.0\text{MHz}$	--	177	--	PF
Output Capacitance	C_{oss}		--	30	--	PF
Reverse Transfer Capacitance	C_{rss}		--	25	--	PF
Switching Characteristics <small>(Note 4)</small>						
Turn-on Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=-10\text{V} I_{\text{D}}=-2\text{A}$ $V_{\text{GS}}=-4.5\text{V} R_{\text{G}}=3.3\Omega$	--	11	--	nS
Turn-on Rise Time	t_r		--	32	--	nS
Turn-Off Delay Time	$t_{\text{d(off)}}$		--	25	--	nS
Turn-Off Fall Time	t_f		--	38	--	nS
Total Gate Charge	Q_g	$V_{\text{DS}}=-10\text{V} I_{\text{D}}=-2\text{A}$ $V_{\text{GS}}=-4.5\text{V}$	--	5.3	--	nC
Gate-Source Charge	Q_{gs}		--	0.7	--	nC
Gate-Drain Charge	Q_{gd}		--	1.4	--	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage <small>(Note 3)</small>	V_{SD}	$V_{\text{GS}}=0\text{V} I_{\text{S}}=-1\text{A}$	--	-0.84	-1.2	V
Diode Forward Current <small>(Note 2)</small>	I_{S}		--	--	-1.2	A

Notes:

① Pulse width limited by maximum allowable junction temperature

② Pulse test ; Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

• Typical Characteristics

Fig1. Typical Output Characteristics

Fig2. Normalized Threshold Voltage Vs. Temperature

Fig3. Typical Transfer Characteristics

Fig4. Drain -Source Voltage vs Gate -Source Voltage

Fig5. Typical Source-Drain Diode Forward Voltage

Fig6. Maximum Safe Operating Area

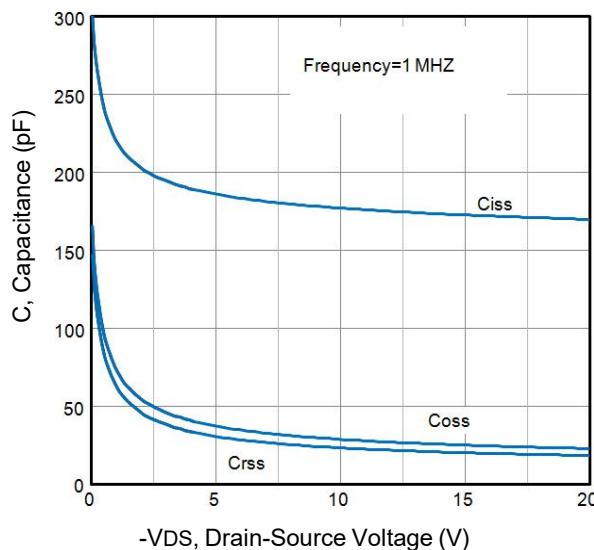


Fig7. Typical Capacitance Vs. Drain-Source Voltage

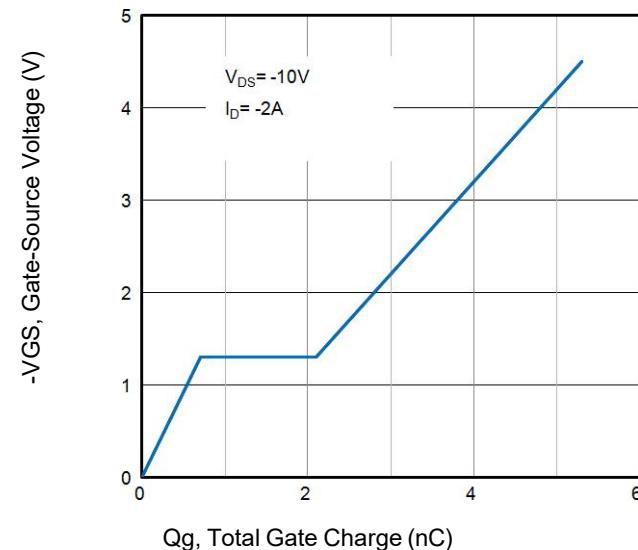


Fig8. Typical Gate Charge Vs. Gate-Source Voltage

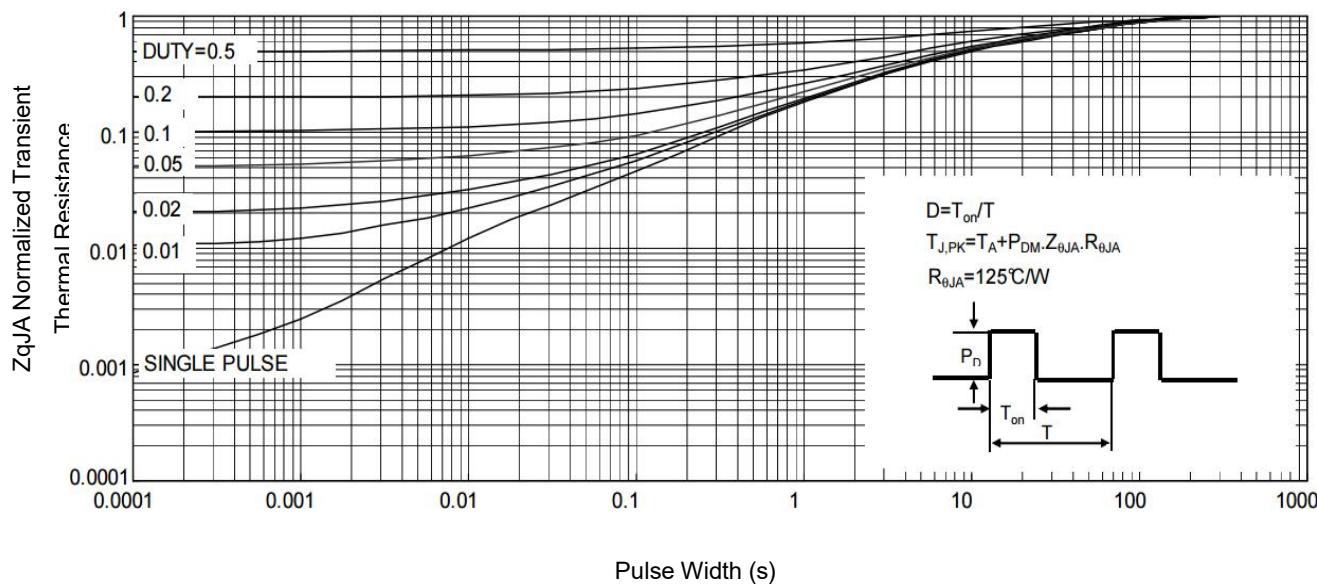


Fig9. Normalized Maximum Transient Thermal Impedance

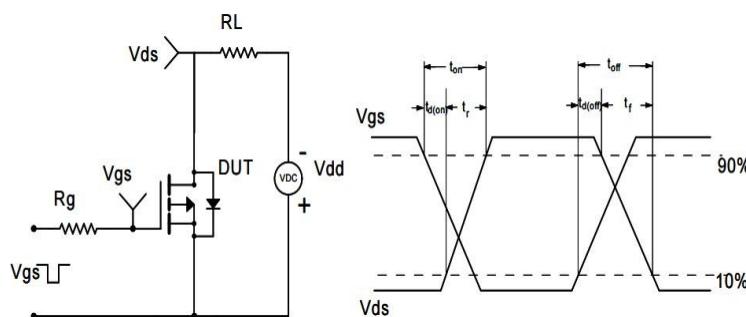
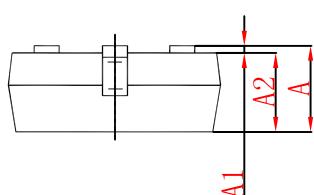
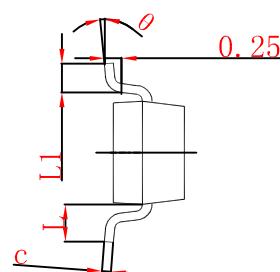
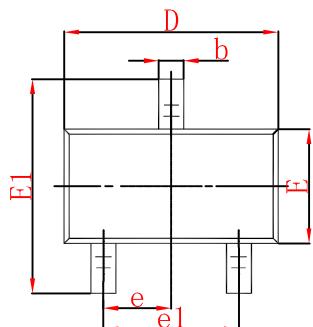
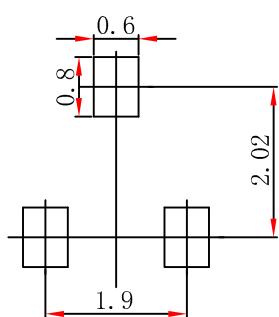


Fig10. Switching Time Test Circuit and waveforms

SOT-23 Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°


Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.